L Number	Hits	Search Text	DB	Time stamp
1	693	electroluminesce\$2 and implant\$3	USPAT;	2004/05/29 11:40
			US-PGPUB:	100,20 11.10
			EPO: JPO:	
			DERWENT;	1.
			IBM TDB	
2	193681	light near emit\$4 near (diode or device or element)	USPAT:	2004/05/29 11:42
			US-PGPUB:	
			EPO, JPO;	
			DERWENT:	,
	_		IBM_TDB	
3	51	(electroluminesce\$2 and implant\$3) and anodiz\$3	USPAT:	2004/05/29 11:43
			US-PGPUB:	
	·		EPO; JPO:	
			DERWENT:	
	- 22		IBM TDB	
4	842	(light near emit\$4 near (diode or device or element)) and	USPAT:	2004/05/29 11:43
		anodiz\$3	US-PGPUB:	
			EPO; JPO;	
			DERWENT;	1
			IBM TDB	
5	22	((electroluminesce\$2 and implant\$3) and anodiz\$3) and	USPAT:	2004/05/29 11:44
• "		(porous near silicon)	US-PGPUB	, ,
			EPO; JPO;	
			DERWENT:	
			IBM TDB	
6	99	((light near emit\$4 near (diode or device or element)) and	USPAT:	2004/05/29 11:44
	• •	anodiz\$3) and (porous near silicon)	US-PGPUB:	,
· [EPO; JPO;	,
			DERWENT;	
<u></u>		And the second s	IBM TDB	•